

ELECTROMETER-ULTRA LOW BIAS CURRENT MODELS 310, 311, 41, 42, AD523

GENERAL DESCRIPTION

Amplifiers with bias currents less than 1pA are classified as suitable for electrometer use where frequency response and voltage drift are usually secondary requirements. Both varactor bridge and FET input designs are employed to achieve these bias currents ranging from one pico amp (10^{-12} A) to ten femptoamps (10^{-14} A).

Available with either inverting, noninverting or differential inputs, these amplifiers are used as current to voltage converters with high impedance transducers such as photomultiplier tubes, flame detectors, pH cells and radiation detectors. To minimize RFI and other noise pickup problems, the varactor modulated amplifiers, operating at 10fA, are available with shielded cases.

VARACTOR BRIDGE ELECTROMETERS MODEL 310 (INVERTING), MODEL 311 (NONINVERTING)

These operational amplifiers feature extremely low input bias currents and high input impedances. They are applicable to a wide range of electrometer applications which have been traditionally fulfilled using vacuum tube types. Because of varactor bridge inputs, the solid state models 310 and 311 are best suited for applications characterized by extremely high source impedance or where infinitesimal currents must be measured or amplified accurately. In principle, the varactor bridge amplifier design is similar to that of the vibrating reed electrometers (parametric), but with the inherent advantages of solid state circuitry.

Typical specifications for models 310 and 311 include open loop gain of 100dB, 2kHz unity gain response, 0.4V/msec slew rate, initial bias current of 10^{-14} A, with 10^{-15} A/°C current stability, and low current and voltage noise of 10^{-15} A and 10μV p-p (1Hz bandwidth) respectively. Two voltage drift selections are available: 310J, 311J with $30\mu\text{V}/^\circ\text{C}$, and 310K, 311K with $10\mu\text{V}/^\circ\text{C}$. Each is housed in an aluminum enclosure for improved shielding.

Model 310, with inverting input only, is most appropriate for use with current source signals such as gas chromatographs flame detectors and photomultiplier tubes. It is also useful for precision long term integrators or where extremely wide dynamic current range is needed as in log compression amplifiers. Current to voltage converters may also be developed using a feedback resistor for setting the conversion scale factor.

Model 311 has a single noninverting input for measuring voltage from very high source impedances where bias currents would create substantial offset errors. Such sources include pH cells or stored capacitor charge as found in long term track and hold applications. Common mode rejection is 100dB at $\pm 25\text{V}$ with $10^{14}\Omega$ impedance to ground for reduced source loading errors.

FET INPUT ELECTROMETERS

MODELS 41, 42, AD523 (MONOLITHIC): This family of FET input amplifiers fully complements the varactor bridge



Model	Lowest Cost High Gain FET		
	J	K	
Open Loop Gain	300,000		
DC Rated Load min	±10V@5mA		
Rated Output min	±10V@5mA		
Frequency Response	1MHz		
Unity Gain, Small Signal	4kHz		
Full Power Response, min	0.25V/μs		
Slewing Rate, min	10ms		
Overload Recovery	10ms		
Input Offset Voltage	±25μV/°C		
Initial, 25°C, (adj. to zero)	±50	±2mV ¹	±25μV/°C
Avg. vs. Temp (0 to 70°C) max vs. Supply Voltage vs. Time	±50	±15	±25μV/°C
Input Bias Current	350fA	100fA	75fA
Initial, 25°C, max	350fA	100fA	75fA
Inverting Input (Varactor)	350fA	100fA	75fA
Non-Inverting Input (Varactor)	350fA	100fA	75fA
Avg. vs. Temp (0 to 70°C)	0, -4pA ³		
Input Impedance	10 ¹³ Ω//3pF		
Differential	10 ¹³ Ω//3pF		
Inverting Input (to common)	10 ¹³ Ω		
Non-Inverting Input (to common)	10 ¹³ Ω		
Common Mode (FET)	10 ¹³ Ω		
Input Noise	6μV		
Voltage, 0.01 to 1Hz, p-p	8μV		
5Hz to 50kHz, rms	5fA		
Current, 0.1 to 10Hz, p-p	---		
1 to 100Hz, rms (Varactor)	---		
Input Voltage Range	±10V		
Common Mode Voltage, min	66dB@±1V		
Common Mode Rejection	±15V		
Max Safe Differential Voltage	±(12 to 18)V		
Power Supply Range (VDC)	±15V@2mA		
Rated Specification (VDC)	0 to +70°C		
Temperature Range	0 to +70°C		
Operating, Rated Specifications	QB-1		
Package Outline	1.1" x 1.1" x 0.57"		
Case Dimensions	QB-1		
Price	1-9 \$32 \$38 \$42		
10-24	\$30 \$36 \$39		

(1)With external 4.99k trim.

(3)Max bias at 70°C.

(2)With trim terminal open.

(4)Signal input only.

designs for electrometer applications. Available in three package sizes, these designs provide high input impedance, sub-picoamp bias currents and improved bandwidth characteristics. They may be used single-ended or differentially for making low level current or voltage measurements from photo/ion current transducers, pH cells, photometers or, in general, where speed and low input capacitance are essential for accurate measurements at high impedance levels as found in automated test systems. Other applications include fast integrators, charge amplifiers, differentiators and long term integrators. In addition, these carrier-less units overcome certain RFI problems which may arise in extremely noisy environments using the varactor bridge modulator types.

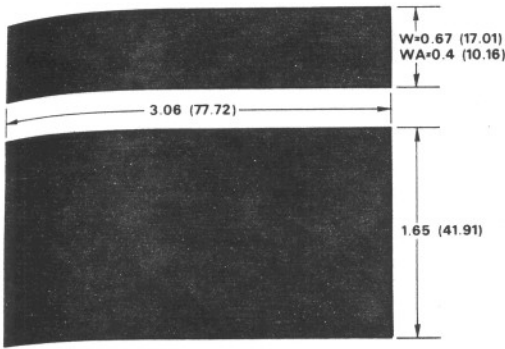
Model 42 J/K/L: Undoubtedly one of the best values for OEM designs, this differential FET amplifier has 110dB open loop gain, for improved closed loop accuracy, 1MHz unity gain response and CMR of 66dB at $\pm 1V$ CMV. It is available in three current selections ranging from 0.35pA to 75fA. Each device features all hermetically sealed semiconductors, with monolithic front end, in a compact module for improved reliability and good thermal transient response.

Model 41 J/K/L: This device combines outstanding bias current and drift specifications with speed and full differential input capability for use in a broad range of electrometer and integrator applications as well as for wideband differential and buffer circuitry. Typical specifications include 50kHz full power response, 94dB CMR at $\pm 5V$ (80dB at $\pm 10V$), 100dB gain for improved closed loop performance, and three bias current and drift selections: 41J, 0.5pA and $25\mu V/^\circ C$; 41K, 0.25pA and $10\mu V/^\circ C$; and 41L, 0.15pA and $25\mu V/^\circ C$. Special packaging techniques assure 10^{13} input impedance, free from internal current leakage paths, and a maximum 4pA bias current rating at $+70^\circ C$.

Model AD523: This unit is a very low bias current IC op amp. It features maximum steady-state bias currents (either input) as low as 0.25pA, in a special low-leakage TO-99 metal can package that minimizes case leakage by utilizing a special guard pin and high resistivity glass insulation. The AD523 is short circuit protected and offset voltage nullable, and features drift of $15\mu V/^\circ C$, slew rate of $4V/\mu sec$, and large signal voltage gain of 25,000 V/V. It is available in J, K, L (0 to $+70^\circ C$) and S ($-55^\circ C$ to $+125^\circ C$) specification versions. (See also Linear IC Section).

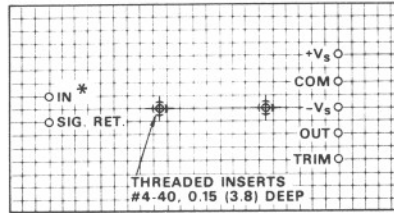
Discrete			Microcircuit				
Wideband High CMR 41			Varactor Inverting 310	Varactor Non-Inverting 311	Differential 0.25pA Guarded Input AD523		
J	K	L	J	K	J	K	L
100,000	100,000	100,000	100,000	100,000	25,000	40,000	40,000
$\pm 10V@5mA$	$\pm 10V@5mA$	$\pm 10V@5mA$	$\pm 10V@5mA$	$\pm 10V@5mA$	$\pm 10V@5mA$		
1MHz 50kHz 3V/ μs 2 μs	2kHz 7Hz 0.4V/ms 10ms	2kHz 7Hz 0.4V/ms 10ms	2kHz 7Hz 0.4V/ms 10ms	2kHz 7Hz 0.4V/ms 10ms	500kHz 50kHz typ 3.0V/ μs 6 μs		
± 25 $\pm 2mV^2$ ± 10 $\pm 10\mu V/^\circ C$ $\pm 25\mu V/mo.$	Adjust to zero ± 30 $\pm 10\mu V/^\circ C$ $\pm 100\mu V/\%$ $\pm 100\mu V/mo.$	Adjust to zero ± 30 $\pm 10\mu V/^\circ C$ $\pm 100\mu V/\%$ $\pm 100\mu V/mo.$	$\pm 50mV$ $\pm 20mV$ $\pm 20mV$ ± 90 ± 30 $\pm 60\mu V/^\circ C$ ± 30 ± 15 $\pm 15\mu V/\%$				
0, -0.5pA -0.25pA -0.15pA	— $\pm 10fA$ $\pm 1nA$ $\pm 1fA/^\circ C^4$	— $\pm 1nA$ $\pm 10fA$ $\pm 1fA/^\circ C^4$	0, -1.0pA -0.5 -0.25pA				
$10^{13} \Omega // 3pF$ — — $10^{13} \Omega$	$3 \times 10^{11} \Omega$ — — —	$3 \times 10^{11} \Omega$ $10^9 \Omega$ $10^{14} \Omega$ —	$10^{12} \Omega$ — — $10^{13} \Omega$				
8 μV 10 μV 5fA —	10 μV 10 μV (1 to 100Hz) 1fA (0.01 to 1Hz) 2fA	10 μV 10 μV (1 to 100Hz) 1fA (0.01 to 1Hz) 2fA	20 μV — — —				
$\pm 10V$ 94dB@ $\pm 5V$ $\pm 15V$	NA NA $\pm 300V$	$\pm 25V$ 100dB@ $\pm 25V$ $\pm 300V$	70dB min 80dB min 80dB min $\pm 10V$				
$\pm(12$ to $18)V$ $\pm 15V@8mA$	$\pm(12$ to $18)V$ $\pm 15V@+15, -6mA$	$\pm(12$ to $18)V$ $\pm 15V@+15, -6mA$	$\pm(5$ to $18)V$ $\pm 15V@7mA$				
0 to $+70^\circ C$ F-2 1.5" x 1.5" x 0.4"	0 to $+70^\circ C$ W-1 3" x 1.65" x 0.67"	0 to $+70^\circ C$ W-1 3" x 1.65" x 0.67"	0 to $+70^\circ C$ TO-99 (guard pin 8 conn. to case)				
\$53 \$64 \$75 \$50 \$59 \$71	\$59 \$95 \$55 \$90	\$62 \$100 \$58 \$95	\$21 \$25 \$28 \$21 \$25 \$28				

W, WA PACKAGES

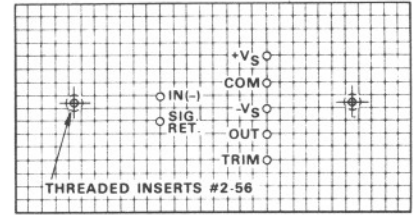


Model	Package	Socket
231	WA-1	AC1014
310	W-1	AC1017
311	W-1	AC1017

W-1

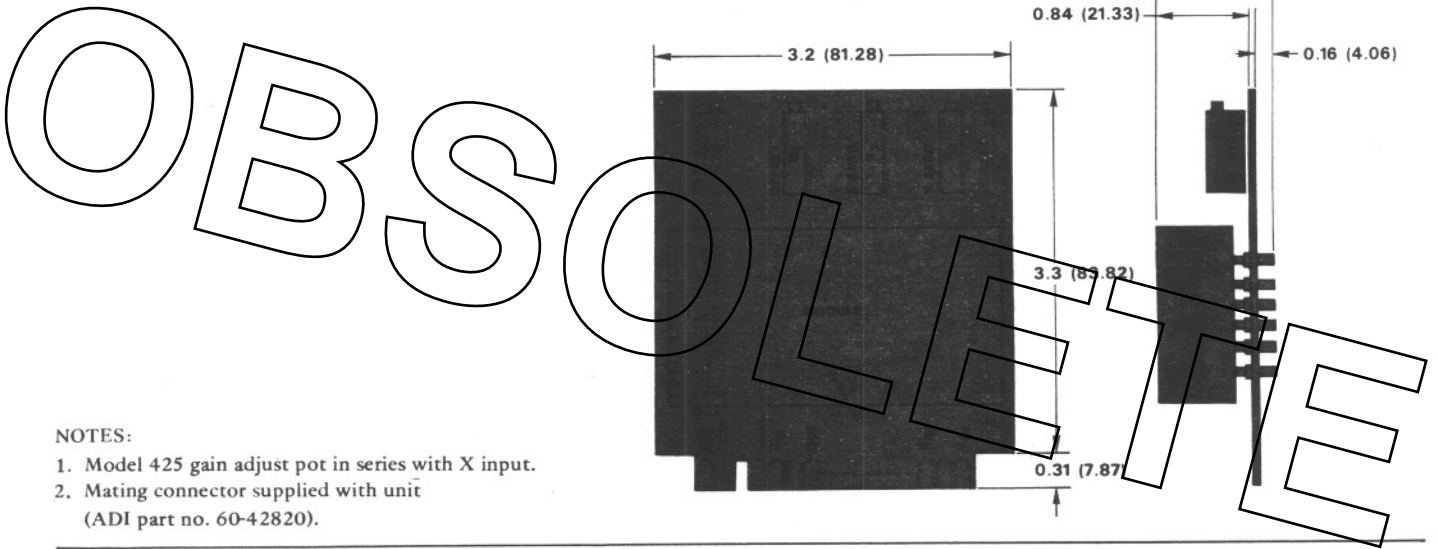


WA-1



* -IN, model 310; +IN, model 311.

MODEL 425 OUTLINE

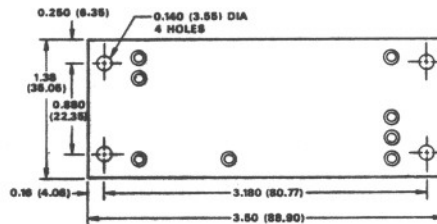


NOTES:

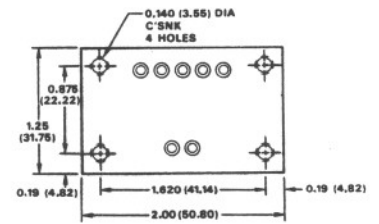
1. Model 425 gain adjust pot in series with X input.
2. Mating connector supplied with unit (ADI part no. 60-42820).

MATING SOCKETS

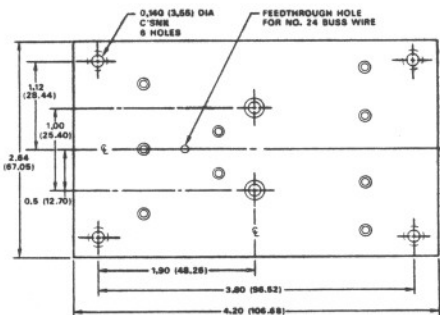
AC1002 @ \$3.75



AC1003 @ \$3.00



AC1007 @ \$8.00

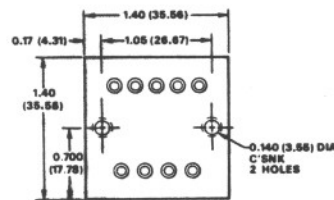


AC1008 @ \$3.25

AC1011 @ \$3.75

AC1016 @ \$3.25

AC1039 @ \$3.25



AC1010 @ \$3.25

